



#### 30V P-Channel Enhancement Mode MOSFET

Voltage -30 V Current -3.8A

#### **Features**

- RDS(ON), VGS@-10V, ID@-3.8A< $65m\Omega$
- RDS(ON) , VGS@-4.5V, ID@-2.6A<80mΩ</li>
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Applications, and Solid-State Relays Drivers: Relay
- Lead free in compliance with EU RoHS 2011/65/EU directive.
- Green molding compound as per IEC61249 Std. (Halogen Free)

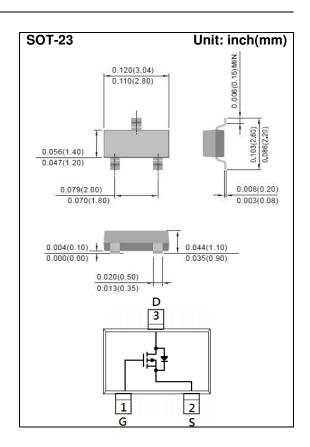
#### **Mechanical Data**

• Case: SOT-23 Package

• Terminals : Solderable per MIL-STD-750, Method 2026

Approx. Weight: 0.0003 ounces, 0.0084 grams

Marking: A07



## Maximum Ratings and Thermal Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

PARAME	SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V <sub>DS</sub>	-30	V
Gate-Source Voltage		$V_{GS}$	<u>+</u> 20	V
Continuous Drain Current		I <sub>D</sub>	-3.8	Α
Pulsed Drain Current		I <sub>DM</sub>	-15.2	Α
Power Dissipation	T <sub>a</sub> =25°C	P <sub>D</sub>	1.25	W
	Derate above 25°C		10	mW/°C
Operating Junction and Storage Temperature Range		$T_{J}$ , $T_{STG}$	-55~150	°C
Typical Thermal resistance				
- Junction to Ambient (Note 3)		$R_{\theta JA}$	100	°C/W





## **Electrical Characteristics** (T<sub>A</sub>=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =-250uA	-30	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ , $I_{D}=-250uA$	-1.0	-1.36	-2.1	V
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =-10V, I <sub>D</sub> =-3.8A	-	52	65	mΩ
		V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-2.6A	-	66	80	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS}$ =-30V, $V_{GS}$ =0V	-	-0.01	-1	uA
Gate-Source Leakage Current	I <sub>GSS</sub>	$V_{GS} = \pm 20V, V_{DS} = 0V$	-	<u>+</u> 10	<u>+</u> 100	nA
Dynamic						
Total Gate Charge	$Q_{g}$	V <sub>DS</sub> =-15V, I <sub>D</sub> =-3.8A, V <sub>GS</sub> =-10V <sup>(Note 1,2)</sup>	-	12	-	nC
Gate-Source Charge	$Q_{gs}$		-	1.7	-	
Gate-Drain Charge	$Q_{gd}$		-	2.3	-	
Input Capacitance	Ciss	V 45V V 0V	-	528	-	pF
Output Capacitance	Coss	V <sub>DS</sub> =-15V, V <sub>GS</sub> =0V, f=1.0MHZ	-	63	-	
Reverse Transfer Capacitance	Crss	I=I.UIVIMZ	-	48	-	
Switching						
Turn-On Delay Time	td <sub>(on)</sub>	V 45V L 0.0A	-	5	-	
Turn-On Rise Time	tr	V <sub>DD</sub> =-15V, I <sub>D</sub> =-3.8A,		33		ns
Turn-Off Delay Time	td <sub>(off)</sub>	$V_{GS}$ =-10V, $R_{G}$ =6 $\Omega$ (Note 1,2)	-	27	-	
Turn-Off Fall Time	tf	n <sub>G</sub> =012		10		
Drain-Source Diode		<del>,</del>				
Maximum Continuous Drain-Source	l <sub>S</sub>		-	-	-1.5	Α
Diode Forward Current						
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> =-1.0A, V <sub>GS</sub> =0V	-	0.76	-1.2	V

#### NOTES:

- 1. Pulse width<300us, Duty cycle<2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Reja is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper
- 4. The maximum current rating is package limited





#### **TYPICAL CHARACTERISTIC CURVES**

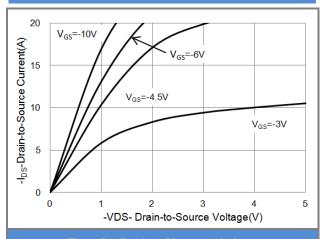


Fig.1 On-Region Characteristics

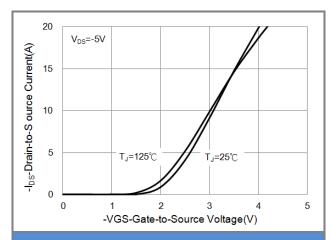


Fig.2 Transfer Characteristics

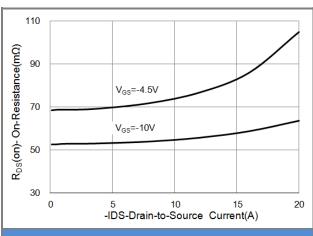


Fig.3 On-Resistance vs. Drain Current

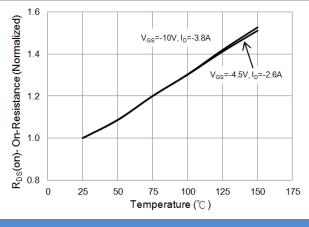
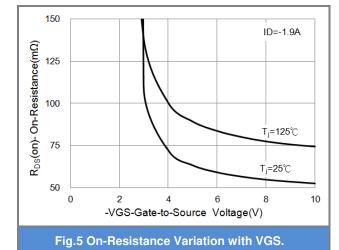
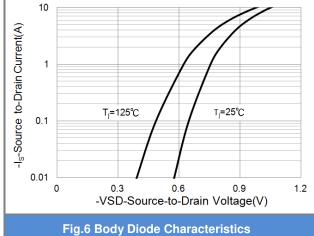


Fig.4 On-Resistance vs. Junction temperature









### **TYPICAL CHARACTERISTIC CURVES**

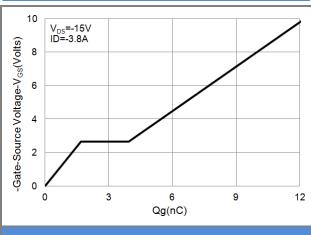


Fig.7 Gate-Charge Characteristics

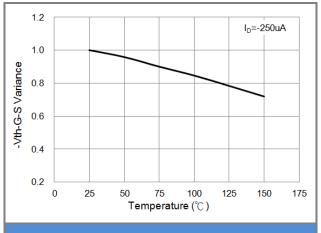


Fig.8 Threshold Voltage Variation with Temperature.

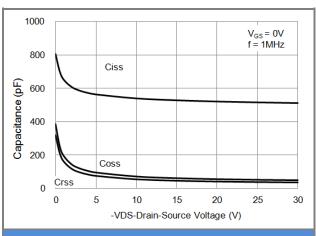


Fig.9 Capacitance vs. Drain-Source Voltage.

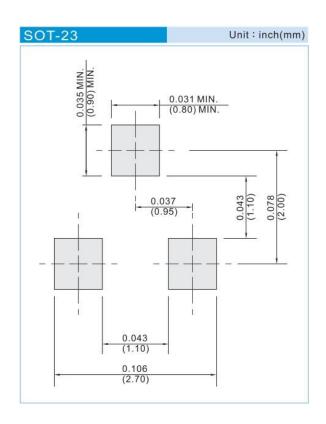




### PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing type	Marking	Version
PJA3407_R1_00001	SOT-23	3K pcs / 7" reel	A07	Halogen free
PJA3407_R2_00001	SOT-23	12K pcs / 13" reel	A07	Halogen free

### **MOUNTING PAD LAYOUT**







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